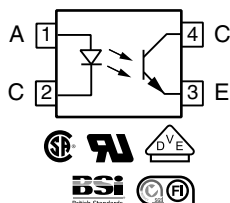
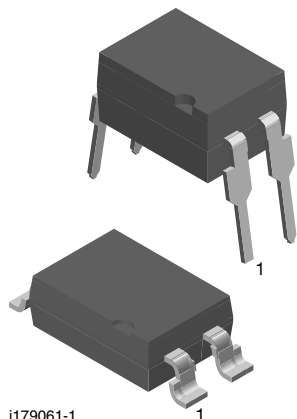




Optocoupler, Phototransistor Output, Low Input Current



FEATURES

- Good CTR linearity depending on forward current
- Low CTR degradation
- High collector emitter voltage, $V_{CE0} = 55\text{ V}$
- Isolation test voltage, 5300 V_{RMS}
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode transient immunity
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT

APPLICATIONS

- Telecom
- Industrial controls
- Battery powered equipment
- Office machines

AGENCY APPROVALS

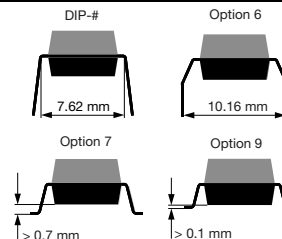
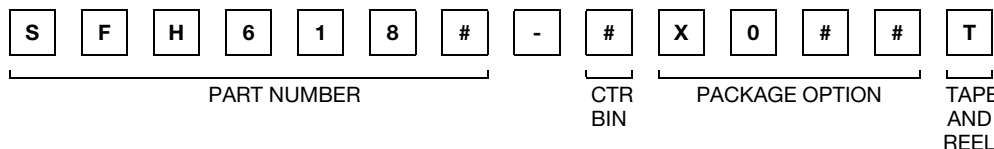
- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO

DESCRIPTION

The SFH618A (DIP) and SFH6186 (SMD) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits. The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm achieved with option 6.

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)			
	1 mA			
UL, CUL	63 to 125	100 to 200	160 to 320	250 to 500
DIP-4	SFH618A-2	SFH618A-3	SFH618A-4	SFH618A-5
DIP-4, 400 mil, option 6	-	SFH618A-3X006	-	-
SMD-4, option 7	-	-	-	SFH618A-5X007T ⁽¹⁾
SMD-4, option 9	SFH6186-2T ⁽¹⁾	SFH6186-3T ⁽¹⁾ , SFH6186-3T1 ⁽²⁾ , SFH6186-3X002T ⁽¹⁾	SFH6186-4T ⁽¹⁾	SFH6186-5T ⁽¹⁾ , SFH6186-5T1 ⁽²⁾
VDE, UL, CUL	63 to 125	100 to 200	160 to 320	250 to 500
DIP-4	-	SFH618A-3X001	SFH618A-4X001	-
DIP-4, 400 mil, option 6	-	SFH618A-3X016	SFH618A-4X016	SFH618A-5X016
SMD-4, option 7	-	SFH618A-3X017T ⁽¹⁾	-	SFH618A-5X017T ⁽¹⁾
SMD-4, option 9	-	SFH6186-3X001T ⁽¹⁾	SFH6186-4X001T	SFH6186-5X001T ⁽¹⁾

Notes

- Additional options may be possible, please contact sales office
- ⁽¹⁾ Also available in tubes, do not put T to the end
- ⁽²⁾ Product is rotated 180° in tape and reel cavity



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	6	V
Power dissipation		P _{diss}	70	mW
Forward current		I _F	60	mA
OUTPUT				
Collector emitter voltage		V _{CEO}	55	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		I _C	50	mA
	t _p ≤ 1 ms	I _C	100	mA
Power dissipation		P _{diss}	150	mW
COUPLER				
Isolation test voltage between emitter and detector	t = 1 s	V _{ISO}	5300	V _{RMS}
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω
Storage temperature range		T _{stg}	- 55 to + 150	°C
Ambient temperature range		T _{amb}	- 55 to + 100	°C
Junction temperature		T _j	125	°C
Soldering temperature ⁽¹⁾	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T _{slid}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

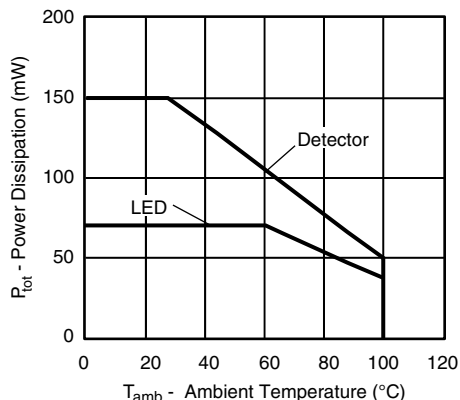


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature



ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I _F = 5 mA		V _F		1.1	1.5	V	
Reverse current	V _R = 6 V		I _R		0.01	10	μA	
Capacitance	V _R = 0 V, f = 1 MHz		C _O		25		pF	
Thermal resistance			R _{thja}		1070		K/W	
OUTPUT								
Collector emitter leakage current	V _{CE} = 10 V		I _{CEO}		10	200	nA	
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz		C _{CE}		7		pF	
Thermal resistance			R _{thja}		500		K/W	
COUPLER								
Collector emitter saturation voltage	I _C = 0.32 mA, I _F = 1 mA	SFH618A-2	V _{CEsat}		0.25	0.4	V	
		SFH6186-2	V _{CEsat}		0.25	0.4	V	
	I _C = 0.5 mA, I _F = 1 mA	SFH618A-3	V _{CEsat}		0.25	0.4	V	
		SFH6186-3	V _{CEsat}		0.25	0.4	V	
	I _C = 0.8 mA, I _F = 1 mA	SFH618A-4	V _{CEsat}		0.25	0.4	V	
		SFH6186-4	V _{CEsat}		0.25	0.4	V	
	I _C = 1.25 mA, I _F = 1 mA	SFH618A-5	V _{CEsat}		0.25	0.4	V	
		SFH6186-5	V _{CEsat}		0.25	0.4	V	
	Coupling capacitance			C _C		0.25		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	I _F = 1 mA, V _{CE} = 0.5 V	SFH618A-2	CTR	63		125	%
		SFH6186-2	CTR	63		125	%
	I _F = 0.5 mA, V _{CE} = 1.5 V	SFH618A-2	CTR	32	75		%
		SFH6186-2	CTR	32	75		%
	I _F = 1 mA, V _{CE} = 0.5 V	SFH618A-3	CTR	100		200	%
		SFH6186-3	CTR	100		200	%
	I _F = 0.5 mA, V _{CE} = 1.5 V	SFH618A-3	CTR	50	120		%
		SFH6186-3	CTR	50	120		%
	I _F = 1 mA, V _{CE} = 0.5 V	SFH618A-4	CTR	160		320	%
		SFH6186-4	CTR	160		320	%
	I _F = 0.5 mA, V _{CE} = 1.5 V	SFH618A-4	CTR	80	200		%
		SFH6186-4	CTR	80	200		%
	I _F = 1 mA, V _{CE} = 0.5 V	SFH618A-5	CTR	250		500	%
		SFH6186-5	CTR	250		500	%
	I _F = 0.5 mA, V _{CE} = 1.5 V	SFH618A-5	CTR	125	300		%
		SFH6186-5	CTR	125	300		%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn on time	V _{CC} = 5 V, I _C = 2 mA, R _L = 100 Ω	t _{on}		6		μs	
Rise time	V _{CC} = 5 V, I _C = 2 mA, R _L = 100 Ω	t _r		3.5		μs	
Turn off time	V _{CC} = 5 V, I _C = 2 mA, R _L = 100 Ω	t _{off}		5.5		μs	
Fall time	V _{CC} = 5 V, I _C = 2 mA, R _L = 100 Ω	t _f		5		μs	

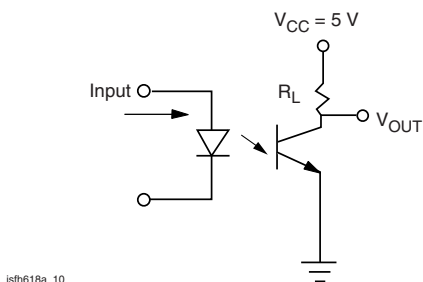


Fig. 2 - Test Circuit

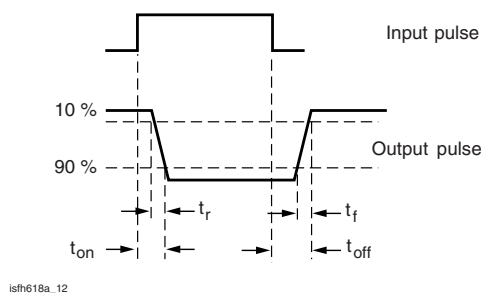


Fig. 3 - Test Circuit and Waveforms

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V_{IOTM}			10000			V
V_{IORM}			890			V
P_{SO}					400	mW
I_{SI}					275	mA
T_{SI}					175	°C
Creepage distance	Standard DIP-4		7			mm
Clearance distance	Standard DIP-4		7			mm
Creepage distance	400 mil DIP-4		8			mm
Clearance distance	400 mil DIP-4		8			mm
Insulation thickness, reinforced rated	per IEC60950 2.10.5.1		0.4			mm

Note

- As per IEC60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

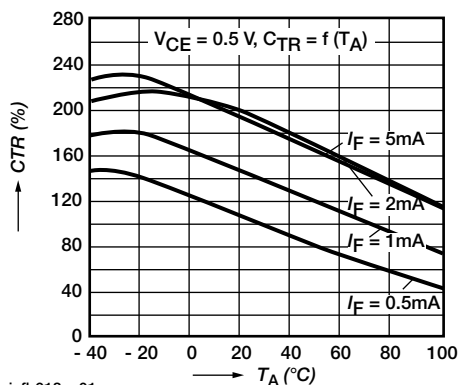


Fig. 4 - Current Transfer Ratio (typ.)

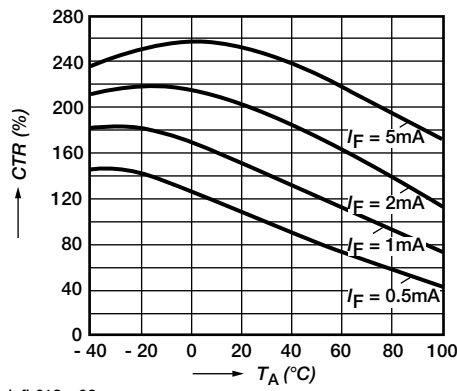


Fig. 5 - Current Transfer Ratio (typ.)

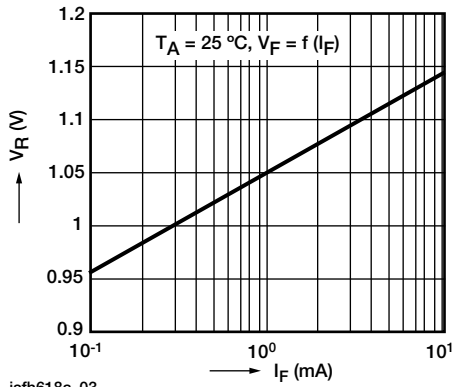


Fig. 6 - Diode Forward Voltage (typ.)

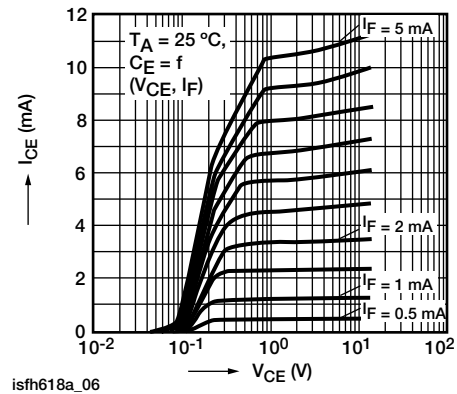


Fig. 9 - Output Characteristics

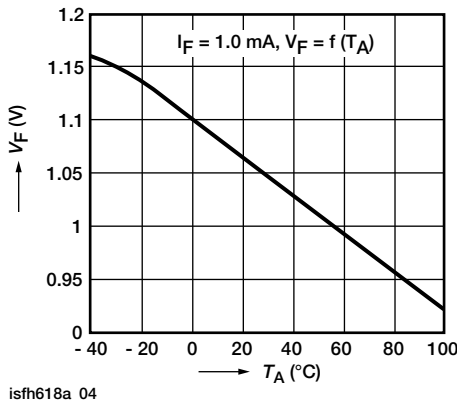


Fig. 7 - Diode Forward Voltage (typ.)

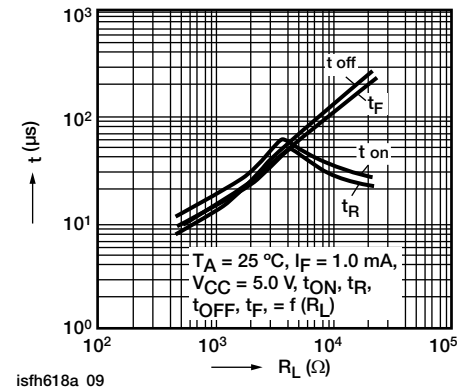


Fig. 10 - Switching Times (typ.)

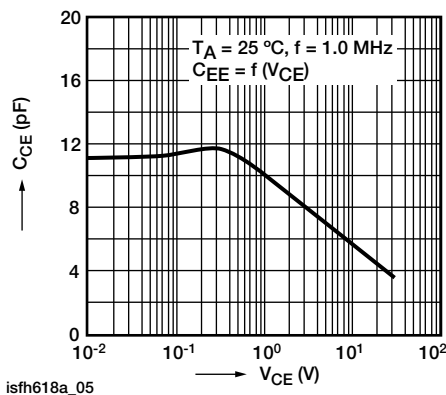
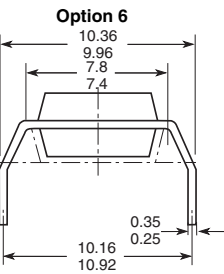
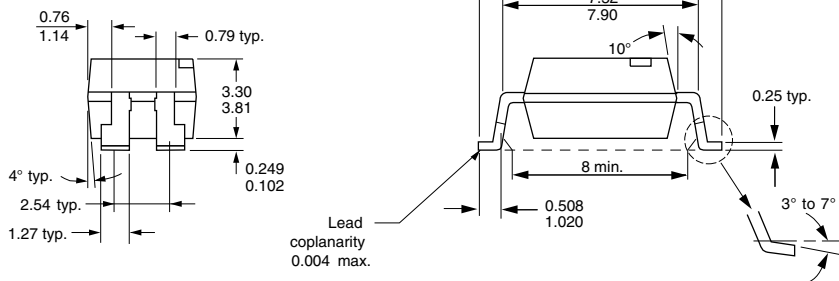
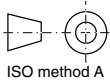
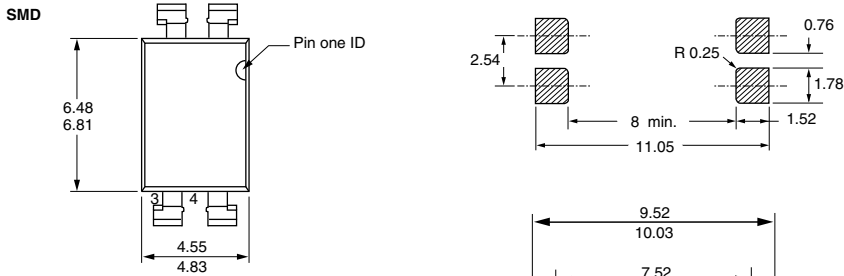
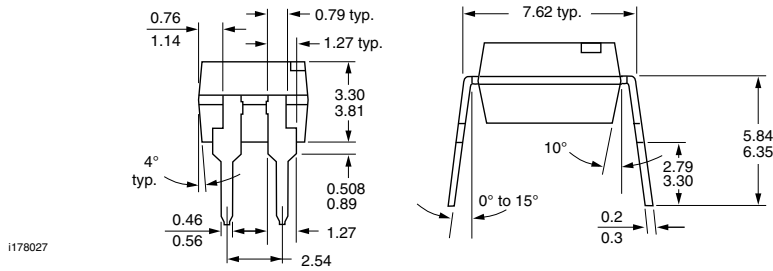
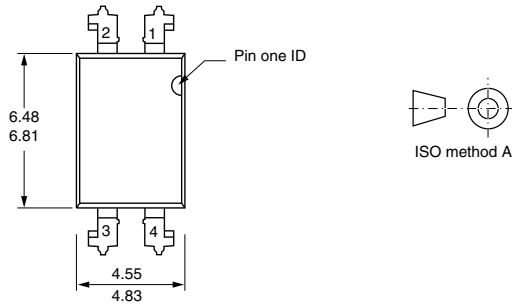


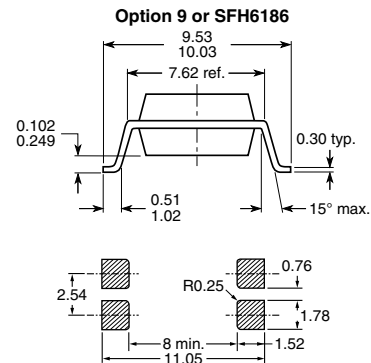
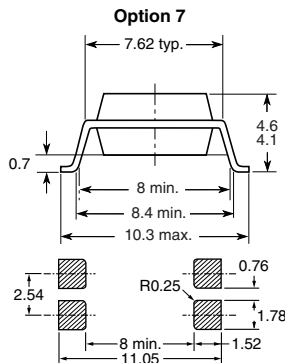
Fig. 8 - Transistor Capacitance



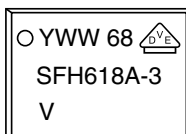
PACKAGE DIMENSIONS in millimeters



18450-11



PACKAGE MARKING





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